DESCRIPTION

The US2AB~US2MB are available in SMB package

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- High efficiency
- Available in SMB package

ORDERING INFORMATION

Package Type	Part Number				
SMB	US2AB				
	US2BB				
	US2DB				
	US2GB US2JB				
					US2KB
	US2MB				
	Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products					

MECHANICAL DATA

Case: SMB

Terminals: Solderable per MIL-STD-750,

Method 2026

Approx. Weight: 0.055g / 0.002oz

PIN DESCRIPTION





MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Paramete	r	Symbol		US2BB	US2DB	US2GB	US2JB	US2KB	US2MB	Unit
		Syllibol	USZAB	USZBB	USZDB	USZGB	USZJB	USZKB	USZIVIB	Offic
Maximum Repetitive Peak		V_{RRM}	50	100	200	400	600	800	1000	V
Reverse Voltage	Reverse Voltage									
Maximum RMS Voltage		V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blockir	Maximum DC Blocking Voltage		50	100	200	400	600	800	1000	V
Maximum Average Forward			2.0							•
Rectified Current at T _C =125°C		I _{F(AV)}								Α
Peak Forward Surge Current										
8.3ms Single Half Sine Wave		I _{FSM}	50							Α
Superimposed on Rated Load										
Maximum Instantaneous			4.0			4.0	4.05		V	
Forward Voltage at 2A		V _F		1.0	1.3		1.65			V
Maximum DC										
Reverse Current at	T _A =25°C		I _R 5.0 100							μА
Rated DC	T _A =125°C	IR								
Blocking Voltage										
Maximum Reverse R	Maximum Reverse Recovery		50							
Time ^{NOTE1}		t _{rr}	50					75		ns
Typical Thermal ResistanceNOTE2		Reja	60						°C/W	
Typical Junction Capacitance		Cj								pF
at V _R =4V, f=1MHz			20							
Operating and Storage										
Temperature Range		T _J , T _{STG}	-55 ~+150							°C

NOTE1: Measured with I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A

NOTE2: P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

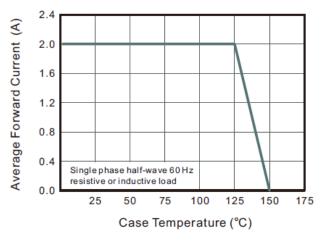


Figure. 3 Typical Forward Characteristics

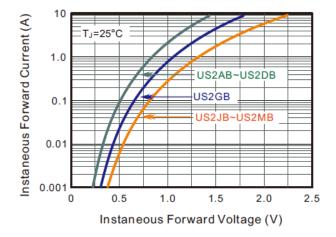


Figure. 2 Typical Reverse Characteristics

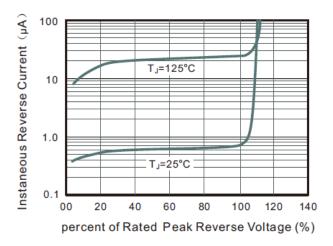
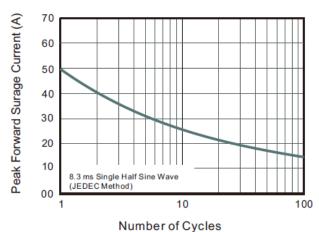


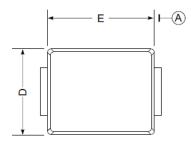
Figure. 4 Maximum Non-Repetitive Peak Forward Surge Current

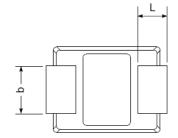


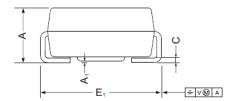
PACKAGE INFORMATION

Dimension in SMB (Unit: mm)

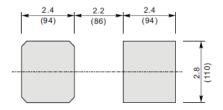
Plastic surface mounted package; 2 leads







The recommended mounting pad size



Unit : $\frac{mm}{(mil)}$

UN	VIT	Α	E	D	E ₁	A ₁	L	С	b
mm	Max	2.44	4.70	3.94	5.59	0.20	1.5	0.305	2.2
	Min	2.13	4.06	3.3	5.08	0.05	0.8	0.152	1.9
mil	Max	96	185	155	220	7.9	59	12	87
	Min	84	160	130	200	2.0	32	6	75

US2AB~US2MB

ULTRAFAST RECOVERY RECTIFIER REVERSE VOLTAGE 50V TO 1000V FORWARD CURRENT 2A

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